



### STM studies of exfoliated black Phosphorus

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Introduction

#### **Black Phosphorous**

- Puckered Layered material of elemental phosphorous  $\rightarrow$
- $\rightarrow$  Most stable allotrope of the phosphorus
- $\rightarrow$  First successfully obtained from white P. (1.2 GPa & 200°C) by Brigdman in 1914



#### A-B = 2.224 A °

B-C = 2.244 A °

#### **Phosphorene**

- Single Layer of Black P  $\rightarrow$
- Honeycomb network similar to Graphene.  $\rightarrow$
- Exfoliated in 2014  $\rightarrow$
- $\rightarrow$  Armchair along X and Zig-Zag along Y







#### Cleaved bP in air - (010) surface

S. L. Yau et. al. Chem, Phys, Lett, 1992, Vol-198, no.-3,4; page-383







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- Cleaved bP in dry N2 measured at 77K and 4.3K
  - Band gap of 0.4 eV
  - Peak at -0.17 V due to a surface state C. D. Zhang et. al. J. Phys. Chem. C 2009, 113, 18823



-0.4 -0.2 0.0 0.2 0.4 Sample Voltage (V)

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> BP single crystal cleaved at RT in UHV – measured at 80K







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Single Vacancies in BP – measured at 4.6K 



BP single crystal cleaved at RT in UHV – measured at 80K

B. Kiraly et. al. arXiv:1702.06753, 22 Feb 2017. а () 0.12 0.08 21 10.04 10 15 Position (nm) h = 0.069 nmh = 0.102 nm



# **Sample Preparation**

- Monolayer epitaxial graphene on silicon carbide is used as the substrate
- bP exfoliation on the substrate and sample transfer to the STM is done inside a glove bag, with N<sub>2</sub> flowing through it – which provides inert atmosphere resulting in high sample quality









# Annealing Experiments

- Sample annealed for 2 hours at temperatures in 50°C succession
- 300°C- 350°C nice temperature for cleaning the surface – atomic resolution images
- 375°C-400°C formation of craters due to increased desorption of the Phosphorus atoms
- beyond 400°C a sudden increase in the surface roughness
- 550°C most of the flakes desorbed









#### **Atomic Resolution**



Measured parameters are in agreement to the reported and predicted values **TABLE 1:** Measured Surface Lattice Constants andTheoretical Optimized Results Together with Previous Dataof Bulk BP

reported by Morita <sup>7</sup>	measured from STM images	theoretical optimized results
a = 3.313  Å b = 10.473  Å c = 4.374  Å $d_1 = 2.222 \text{ Å}, \alpha_1 = 96.5^{\circ}$ $d_2 = 2.777 \text{ Å}, \alpha_2 = 101.9^{\circ}$	a = 3.33  Å c = 4.33  Å	a = 3.28  Å b = 10.37  Å c = 4.35  Å

Morita, A et. al. Appl. Phys. A: Mater. Sci. Proc. 1986, 39, 227.

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#### **Atomic Resolution**

— Profile 1

0.4

e and nanoTechnology

0.5

0.6





# bP desorption with annealing

Xiaolong Liu et. al., J. Phys. Chem. Lett. 2015, 6, 773.



TEM image of eye shaped crack opening on heating bP flake at 400°C for 5, 8 and 12 min.

- decomposition of 2D BP is observed to occur at ~400 °C in vacuum, in contrast to the 550 °C bulk BP sublimation temperature
- This decomposition initiates via eyeshaped cracks along the [001] direction









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M. F. Deschenes et. al., J. Phys. Chem. Lett. 2016, 7, 1667.



Bright-field LEEM snapshots of hole expansion during sublimation of exfoliated bP. Two seconds between each image from (a) to (h) recorded respectively at the following temperatures: 486 °C, 488 °C, 490 °C, 491 °C, 493 °C, 495 °C, 497 °C, and 499 °C.

- Sublimation manifests itself above 375 ± 20 °C
- Faceted holes with the long axis aligned along the [100] direction, in contrast to what was reported earlier

















Measured Unit cell parameters A=0.367 nm, C=0.598 nm









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– Profile 1

30





20



– Profile 1

30





20

x [nm]

















**C** [001]









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#### First STM on exfoliated bP flakes







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- Glove bag facilitates getting high quality samples



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- Surface evolution with temperature









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- Glove bag facilitates getting high quality samples
- Surface evolution with temperature
- Crater alignment to crystal lattice











# Acknowledgement



#### SCUOLA Normale Superiore





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# PhosFun Project

Thank you for your attention